NSN 5961-00-401-7647

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-401-7647 **Inclosure Material:** Glass and metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Bracket and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 600.0 breakover voltage, dc **Current Rating Per Characteristic:** 60.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0